

## 1. General description

The BGA3131 is an upstream amplifier meeting the Data Over Cable Service Interface Specifications (DOCSIS 3.1). It is designed for cable modem, CATV set top box and VoIP modem applications. The device operates from 5 MHz to 205 MHz. The BGA3131 provides 58 dB gain control range in 1 dB increments with high incremental accuracy. Its maximum gain setting delivers 37 dB voltage gain and a superior linear performance.

It supports the DOCSIS 3.1 output power levels while meeting the stringent ACLR requirements.

The BGA3131 operates at 5 V supply. The gain is controlled via a 3-wire serial interface (SPI-Bus). The current consumption can be reduced in 4 steps via the serial interface. This interface enables the user to optimize between DC power efficiency and linearity. In addition, the current is automatically reduced at lower gain settings while preserving the linearity performance. In disable mode, the device draws typically 25 mA while it can be still programmed to new gain and current settings.

The BGA3131 is housed in 20 pins 5 mm  $\times$  5 mm leadless HVQFN package.

## 2. Features and benefits

- **58** dB gain control range in 1 dB steps using a 3-wire serial interface
- 5 MHz to 205 MHz frequency operating range
- $\pm$  0.4 dB incremental gain step accuracy
- Maximum voltage gain 37 dB
- Excellent IMD3 of –60 dBc at 68 dBmV total output power
- Excellent second harmonic level of -60 dBc at 68 dBmV total output power
- Excellent third harmonic level of -60 dBc at 68 dBmV total output power
- Excellent noise figure of 6.5 dB at maximum gain
- Capable of transmitting modulated carriers while meeting the DOCSIS 3.1 ACLR specification. At an output power of 65 dBmV at the F-connector (assuming 3 dB of output loss), the typical ACLR is–64 dBc
- 5 V single supply operation
- Excellent ESD protection at all pins
- Unconditionally stable
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)



# 3. Applications

- DOCSIS 3.1 and 3.0 cable modems
- VoIP modems
- Set-top boxes

## 4. Quick reference data

#### Table 1. Quick reference data

Typical values at  $V_{CC} = 5 V$ ; current setting = 3 mA; gain setting 50 up to and including 63;  $T_{case} = 25 C$ ;  $Z_{i(dif)} = 200 \Omega$ ;  $Z_{o(se)} = 75 \Omega$ ; voltage gain does include loss due to output transformer; unless otherwise specified. All RF parameters are measured on an application board with the circuit as shown in <u>Figure 12</u> and components implemented as listed in <u>Table 15</u>.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CC</sub>	supply current	transmit-enable mode; TX_EN = HIGH	610	660	720	mA
		transmit-disable mode; TX_EN = LOW	-	25	-	mA
Gv	voltage gain	gain code = 111111 [1][2]	-	37	-	dB
NF	noise figure	transmit-enable mode; gain code = 111111	-	6.5	-	dB
α <sub>2H</sub>	second harmonic level	transmit-enable mode; gain code = 111111; $P_i(RMS) = 31.0 \text{ dBmV}; P_L(RMS) = 68.0 \text{ dBmV}$ into 75 $\Omega$ impedance	-	-65	-	dBc
α <sub>3H</sub>	third harmonic level	transmit-enable mode; gain code = 111111; $P_i(RMS) = 31.0 \text{ dBmV}; P_L(RMS) = 68.0 \text{ dBmV}$ into 75 $\Omega$ impedance	-	-65	-	dBc
IMD3	third-order intermodulation distortion	transmit-enable mode; gain code = 111111; $P_L(RMS) = 65.0 \text{ dBmV}$ per tone into 75 $\Omega$ impedance	-	-60	-	dBc
P <sub>L(1dB)</sub>	output power at 1 dB gain compression	CW input signal RMS value; frequency = 205 MHz	-	78	-	dBmV

[1] P<sub>i</sub> <= 30 dBmV.

[2] Excluding 5.7 dB loss of resistive matching circuit, to match 75  $\Omega$  to 50  $\Omega$ .

#### Table 2. ACLR quick reference data

Typical values at  $V_{CC} = 5 V$ ; current setting = 3 mA; Gain setting 60;  $T_{case} = 25 \ ^{\circ}C$ ;  $Z_{i(dif)} = 200 \ \Omega$ :  $Z_{o(se)} = 75 \ \Omega$ ; channel bandwidth = 192 MHz; integration bandwidth = 9.6 MHz; f = 5 MHz to 205 MHz; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
DOCSIS	3.1					
ACLR	adjacent channel leakage ratio	$P_i(RMS) = 34 \text{ dBmV}; P_L(RMS) = 68 \text{ dBmV}.$ Channel configuration: channel bandwidth is 192 MHz, with exclusion band at 147.5 MHz; with a bandwidth of 9.6 MHz. Input signal with a PAPR of 13 dB	-	-64	-58	dBc

# 5. Ordering information

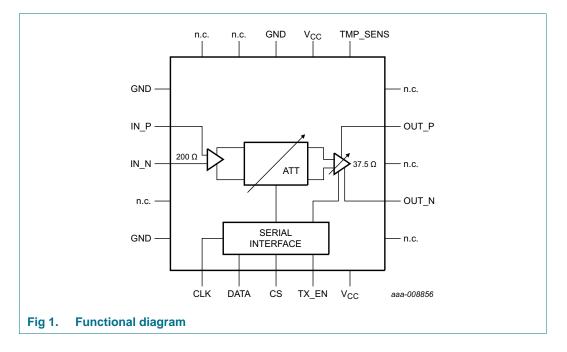
#### Table 3.Ordering information

Type number	Package	Package							
Name Description									
BGA3131	HVQFN20	plastic thermal enhanced very thin quad flat package; no leads; 20 terminals; body 5 $\times$ 5 $\times$ 0.85 mm	SOT662-1						

BGA3131

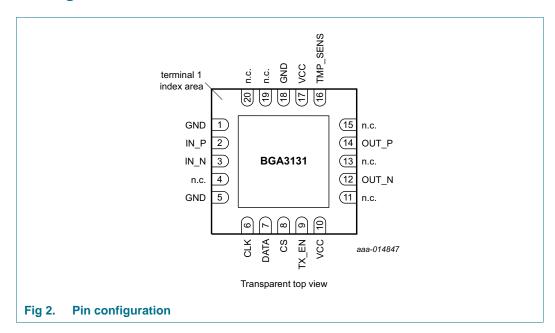
**DOCSIS 3.1 upstream amplifier** 

# 6. Functional diagram



# 7. Pinning information

## 7.1 Pinning



## 7.2 Pin description

Table 4.Pin de	scription	
Symbol	Pin	Description
GND	1	ground
IN_P	2	amplifier input +
IN_N	3	amplifier input –
n.c. [1]	4	not connected
GND	5	ground
CLK	6	clock
DATA	7	data
CS	8	chip select
TX_EN	9	transmit enable active high
V <sub>CC</sub>	10	supply voltage
n.c. [1]	11	not connected
OUT_N	12	amplifier output -
n.c. [1]	13	not connected, pin can be left open, grounded or connected to the center tap voltage in the application
OUT_P	14	amplifier output +
n.c. [1]	15	not connected
TMP_SENS	16	temperature sense
V <sub>CC</sub>	17	supply voltage
GND	18	ground
n.c. [1]	19	not connected
n.c. [1]	20	not connected
GND	die paddle	ground

[1] not connected pins can either be left open or grounded in the application.

## 8. Functional description

## 8.1 Logic programming

The programming word is set through a shift register. It uses the data of the SPI bus (pin name DATA), clock (pin name CLK), and enable (pin name TX\_EN) lines. By default, the data is entered in order with the most significant bit (MSB) first and the least significant bit (LSB) last. The Chip Select line (CS) must be low during the data entry, then set high to sample the shift register. The rising edge of the clock pulse shifts each data value into the shift register. When the register is programmed, the new settings take effect:

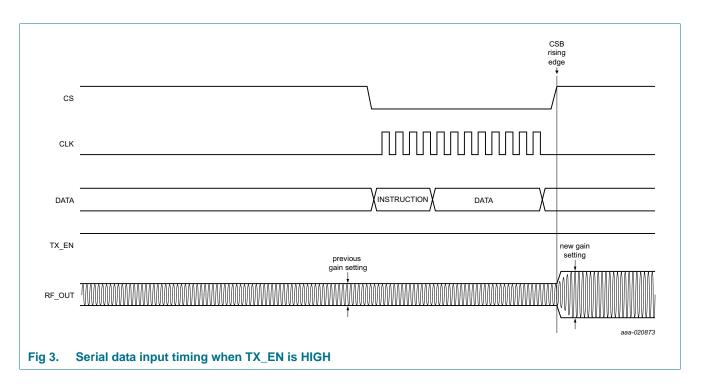
- on the rising, edge of CS, IF TX\_EN is HIGH
- on the rising, edge of TX\_EN if TX\_EN is LOW

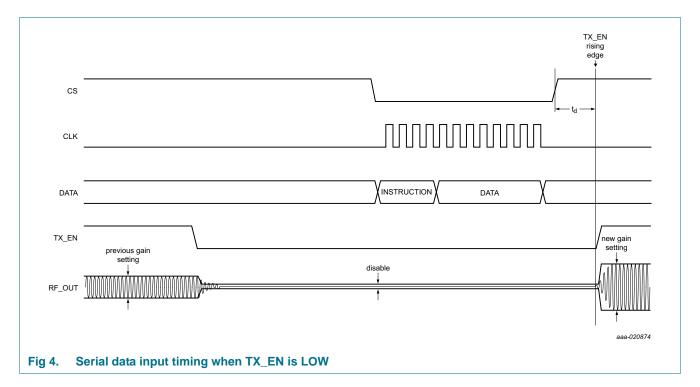
**DOCSIS 3.1 upstream amplifier** 

Table 5.	Programming register											
Data bit	11	10	9	8	7	6	5	4	3	2	1	0
Function Register address Current settings <sup>[1]</sup>				attenuation (gain) settings <sup>[2]</sup>								
Settings	0	0	0	0	C[1]	C[0]	G[5]	G[4]	G[3]	G[2]	G[1]	G[0]
Initialize	0	0	0	1	Soft reset (mirror)	LSB first (mirror)	ASC address (mirror)	16b mode (mirror)	16b mode	ASC address	LSB first	Soft reset
Reserved	0	0	1	0	0	0	0	0	0	0	0	0
Reserved	0	0	1	1	0	0	0	0	0	0	0	0

[1] For current bit settings, see <u>Table 7</u>.

[2] For gain bit settings, see <u>Table 6</u>.





## 8.2 Register settings

## 8.2.1 Register address

Only addresses 0000 to 0011 are used. Using any other addresses do not affect the VGA. Address 0000 is used to configure attenuation and current parameters of the device. Address 0001 is used to configure the SPI interface specifically. Addresses 0010 and 0011 are reserved, and must be kept at value 0.

## 8.2.2 Gain/attenuator setting

The gain shall be controlled via the SPI bus. Data bits D0 through D5 set the gain/attenuator level, with 111111 being the min attenuation setting, and 000101 being the maximum attenuation setting. A new gain/attenuator setting can be loaded while the VGA is on (transmit-enable).

able of Gall Sollings					
Gain setting G[5:0] <sup>[1]</sup>	Typical gain				
binary notation	(dB)				
000000 to 000101	0 to 5	-21			
000110	6	-20			
111110	62	36			
111111	63	37			

#### Table 6. Gain settings

[1] With every increment of the gain setting between 000101 (5) and 111111 (63), the typical gain increases accordingly.

## 8.2.3 Output stage current setting

The current (of the output stage) shall be controlled via the 3-wire bus. Data bits D6 and D7 set the current. Setting 11 sets the maximum current for maximum linearity. The current can be lowered for improved efficiency at lower output power levels, or lower linearity requirements. Setting 00 sets the minimum current. A new current setting can be loaded while the VGA is on (transmit-enable).

# Table 7.Supply current settingsAt gain setting 63.

Current setting C[1:0]		Typical supply current							
binary notation decimal notation		(mA)							
00 0		350							
01	1	410							
10 2		480							
11	3	660							

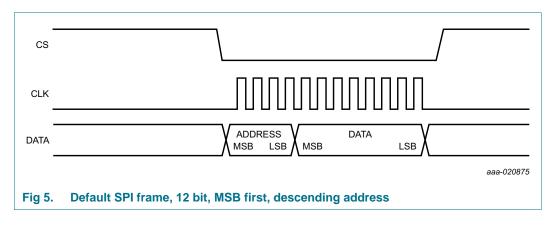
The current is automatically reduced at lower gain settings while preserving the linearity performance.

#### Table 8. Device current setting versus gain setting

Gain setting		Typical current (r	ical current (mA)						
Attenuation bit [5.0]	H value	Current setting C[1:0] = 00	Current setting C[1:0] = 01	Current setting C[1:0] = 10	Current setting C[1:0] = 11	Comments			
111111	0x3F	315	410	480	660	Max.gain (code = 63)			
110001	0x31	280	315	345	370	Gain code = 49			
101011	0x2B	290	320	350	375	Gain code = 43			
100101	0x25	240	260	260	330	Gain code = 37			
011001	0x19	220	235	235	250	Gain code = 25			

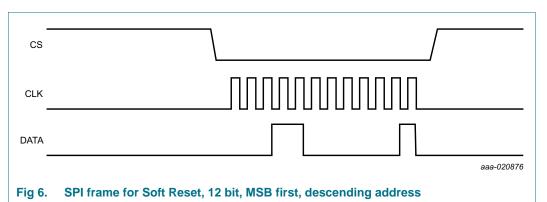
## 8.2.4 SPI Initialize register

The SPI receiver may be configured in several communication modes. By default, the device is waiting for a 12 bit, MSB first SPI frame. In that case, the address field is 4 bit wide and the data field is 8 bit wide. Using the Initialize register at address 0x01 allows switching the device to different SPI modes. Register 0x01 contains four effective bits, but programmed with the mirror value of the 4 LSBs in the 4 MSBs.



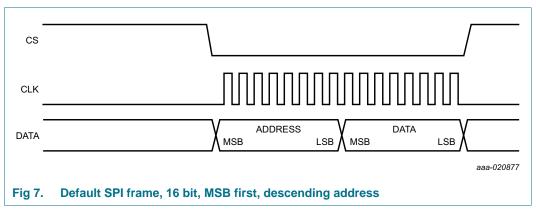
#### 8.2.4.1 SPI Soft Reset

By setting bits *Soft\_reset AND Soft\_reset (mirror)* at address 0x01, the device is set to its default state (maximum gain).



#### 8.2.4.2 SPI 16-bit mode

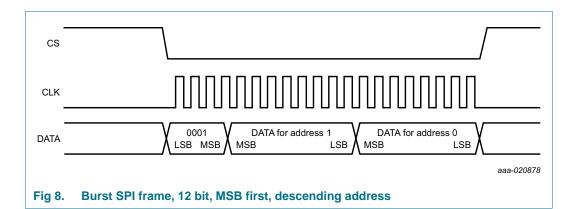
By default, the SPI frame is made of 4 bits for address and a multiple of 8 bits for data. By setting bits 16b\_mode AND 16b\_mode (mirror) at address 0x01, the device is configured such that the next SPI command will be a 16-bit command. Address is sent on 8 bits, whereas data is a multiple of 8 bits.

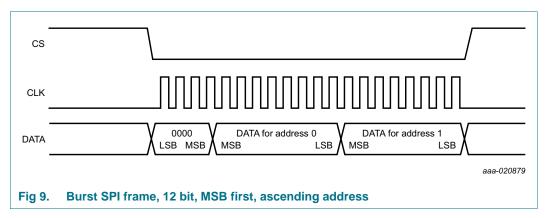


#### 8.2.4.3 SPI ascending address

By default, the SPI slave can be programmed with a single SPI frame. The SPI contains a start address and several data bytes to be written at the start address. It has an auto decrementing mechanism to store data in the corresponding register. By setting bits *asc\_addr* AND *asc\_addr* (*mirror*) at address 0x01, the device is configured so that the internal addresses are auto-incremented instead of auto-decremented.

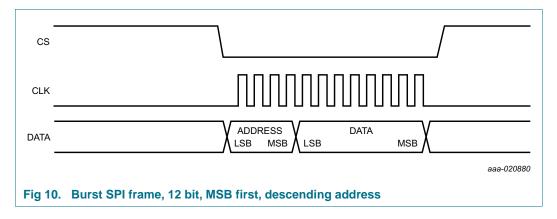
#### **DOCSIS 3.1 upstream amplifier**





#### 8.2.4.4 SPI LSB first

By default, the SPI slave waits for the MSB data first. By setting bits *lsb\_first* AND *lsb\_first* (*mirror*) at address 0x01, the device is configured. The first bit received is considered as the LSB of each field (address and data).



## 8.3 TX enable / TX disable

The amplifier can be disabled or enabled by making TX\_EN (pin 9) LOW or HIGH. A LOW to HIGH TX enable transition enables new programmed settings. If no new settings are programmed, the last programmed setting is reactivated.

# 9. Limiting values

#### Table 9. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Absolute maximum ratings are given as limiting values of stress conditions during operation, that must not be exceeded under the worst probable conditions.

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-	6.0	V
li	input current	on pin TMP_SENS		-	1	mA
Vi	input voltage	on pin IN_P		-0.5	+6.0	V
		on pin IN_N		-0.5	+6.0	V
		on pin CLK	<u>[1]</u>	-0.5	+6.0	V
		on pin DATA	<u>[1]</u>	-0.5	+6.0	V
		on pin CS	[1]	-0.5	+6.0	V
		on pin TX_EN	[1]	-0.5	+6.0	V
		on pin OUT_N		-0.5	+6.0	V
		on pin OUT_P		-0.5	+6.0	V
P <sub>i(max)</sub>	maximum input power			-	60	dBmV
T <sub>stg</sub>	storage temperature			-55	+150	°C
Tj	junction temperature			-	150	°C
V <sub>ESD</sub>	electrostatic discharge voltage	Human Body Model (HBM); according to JEDEC standard 22-A114E	[2]	-	±4	kV
		Charged Device Model (CDM); according to JEDEC standard 22-C101B	[2]	-	±2	kV
f <sub>SPI</sub>	SPI frequency	Master writes to slave; load on DATA line 30 pF maximum. Under nominal $V_{\rm IL}$ and $V_{\rm IH}$ levels		-	25	MHz

[1] All digital pins must not exceed V<sub>CC</sub> as the internal ESD circuit can be damaged. To prevent this damage, it is recommended that control pins are limited to a maximum of 5 mA.

[2] Stressed with pulses of 200 ms in duration.

# **10. Thermal characteristics**

Symbol	Parameter Conditions					
R <sub>th(j-bop)</sub>	thermal resistance from junction to bottom of package	Still air, natural convection [1]	6.1	K/W		
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	Still air, natural convection [1]	29.3	K/W		
Ψ <sub>(j-top)</sub>	thermal characterization parameter from junction to top of package	Still air, natural convection [1]	9.9	K/W		

[1] Simulated using final element method model resembling the device mounted on the application board. See Figure 13.

BGA3131 Product data sheet For more thermal details, refer to the BGA3131 *Thermal management guidelines AN11753* at <u>www.nxp.com</u>.

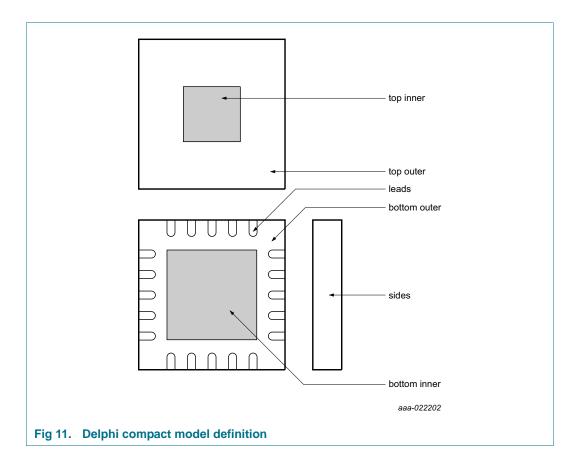
## **10.1 Thermal compact model**

Compact thermal model parameters (Delphi compact model), definitions according to Figure 11

#### Table 11. Delphi model parameters<sup>[1]</sup>

R <sub>th</sub> (K/W)	junction	top inner	top outer	bottom inner	bottom outer	sides	leads	surface areas [mm <sup>2</sup> ]
junction		201		6.17				
top inner			1207	543	1330			4.27
top outer				114	60.4		222	20.7
bottom inner					53.8	315	311	9.53
bottom outer							37.8	12.6
sides							101	17.0
leads								2.85

[1] Cells are intentionally left empty.



# **11. Static characteristics**

#### Table 12. Characteristics

Typical values at  $V_{CC} = 5 V$ ; current setting = 3 mA; gain setting 50 up to and including 63;  $T_{case} = 25 \ ^{\circ}C$ ;  $Z_{i(dif)} = 200 \Omega$ ;  $Z_{o(se)} = 75 \Omega$ ; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CC</sub>	supply voltage		4.75	5.0	5.25	V
I <sub>CC</sub>	supply current	transmit-enable mode; TX_EN = HIGH	610	660	720	mA
		transmit-disable mode; TX_EN = LOW	-	25	-	mA
V <sub>IH</sub>	HIGH-level input voltage	[1]	1.8	-	V <sub>CC</sub> + 0.6	V
V <sub>IL</sub>	LOW-level input voltage	[1]	0	-	0.8	V
Р	power dissipation		-	3.3		W

[1] Voltage on the control pins.

# **12. Dynamic characteristics**

#### Table 13. Characteristics

Typical values at  $V_{CC} = 5$  V; current setting = 3 mA; gain setting 15 up to and including 63;  $T_{case} = 25$  °C;  $Z_{i(dif)} = 200 \Omega$ ;  $Z_{o(se)} = 75 \Omega$ ; voltage gain does include loss due to output transformer; unless otherwise specified. All RF parameters are measured on an application board with the circuit as shown in Figure 12 and components implemented as listed in Table 15.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Gv	voltage gain	gain code = 111111	[1][2]	-	37	-	dB
		gain code = 001111	[1][2]	-	-11	-	dB
G <sub>flat</sub>	gain flatness	f = 5 MHz to 205 MHz	<u>[1]</u>	-	$\pm 0.5$	-	dB
RL <sub>out</sub>	output return loss	transmit mode enable over all gain settings, measured in 75 $\boldsymbol{\Omega}$ system		-	14	-	dB
		transmit mode disable over all gain settings, measured in 75 $\Omega$ system		-	12	-	dB
RL <sub>in</sub>	input return loss	transmit mode enable overall gain settings, measured in 200 $\Omega$ system		-	20	-	dB
		transmit modes disable overall gain settings, measured in 200 $\Omega$ system		-	20	-	dB
G <sub>step</sub>	gain step		[1]	-	1.0	-	dB
E <sub>G(dif)</sub>	differential gain error		[1]	-	± 0.4	-	dB
R <sub>i(dif)</sub>	differential input resistance			-	200	-	Ω
R <sub>o(dif)</sub>	differential output resistance			-	37.5	-	Ω
f <sub>range</sub>	frequency range			5	-	205	MHz
$\alpha_{isol}$	isolation	transmit-disable mode; TX_EN = LOW; f = 205 MHz		-	60	-	dB
NF	noise figure	transmit mode; gain code = 111111		-	6.5	-	dB
		transmit mode; gain code = 100110		-	15	-	dB
t <sub>sw(G)</sub>	gain switch time	transmit-disable/transmit-enable transient duration		-	3.0	-	μS
		transmit-enable/transmit-disable transient duration		-	0.5	-	μS

#### Table 13. Characteristics ... continued

Typical values at  $V_{CC} = 5$  V; current setting = 3 mA; gain setting 15 up to and including 63;  $T_{case} = 25$  °C;  $Z_{i(dif)} = 200 \Omega$ ;  $Z_{o(se)} = 75 \Omega$ ; voltage gain does include loss due to output transformer; unless otherwise specified. All RF parameters are measured on an application board with the circuit as shown in <u>Figure 12</u> and components implemented as listed in <u>Table 15</u>.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>trt</sub>	transient voltage	transmit-disable/transmit-enable transient step size; peak value					
		≥ 58 dBmV output power	<u>[3][4]</u>	-	45	-	mV
		52 dBmV output power	<u>[3][4]</u>	-	15	-	mV
		46 dBmV output power	<u>[3][4]</u>	-	10	-	mV
		40 dBmV output power	<u>[3][4]</u>	-	5	-	mV
		≤ 34 dBmV output power	<u>[3][4]</u>	-	3	-	mV
α <sub>2H</sub>	second harmonic level	transmit-enable mode; gain code = 111111; $P_i = 31.0 \text{ dBmV(rms)}; P_L = 68.0 \text{ dBmV(rms)}$ into 75 $\Omega$ impedance		-	-65	-	dBc
α <sub>3H</sub>	third harmonic level	transmit-enable mode; gain code = 111111; $P_i = 31.0 \text{ dBmV(rms)}; P_L = 68.0 \text{ dBmV(rms)}$ into 75 $\Omega$ impedance		-	-65	-	dBc
IMD3	third-order intermodulation distortion	transmit-enable mode; gain code = 111111; $P_L = 65 \text{ dBmV(rms)}$ per tone into 75 $\Omega$ impedance		-	-60	-	dBc
P <sub>L(1dB)</sub>	output power at 1 dB gain compression	CW input signal RMS value; frequency = 205 MHz		-	78	-	dBmV

 $[1] \quad P_i \leq 30 \ dBmV.$ 

[2] Excluding loss of resistive matching circuit, to match  $75\Omega$  to  $50 \Omega$ .

[3] Measured at the output of the output balun.

[4] Assume 3 dB loss between by output of the balun and F-connector in the final application.

#### Table 14. ACLR characteristics

Typical values at  $V_{CC} = 5$  V; current setting = 3 mA; Gain setting 60;  $T_{case} = 25$  °C;  $Z_{i(dif)} = 200 \Omega$ :  $Z_{o(se)} = 75 \Omega$ ; channel bandwidth = 192 MHz; integration bandwidth = 9.6 MHz; f = 5 MHz to 205 MHz; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
DOCSIS	3.1					
ACLR	adjacent channel leakage ratio	$P_i(RMS) = 34 \text{ dBmV}; P_L(RMS) = 68 \text{ dBmV}.$ Channel configuration: channel bandwidth is 192 MHz, with exclusion band at 147.5 MHz; with a bandwidth of 9.6 MHz. Input signal with a PAPR of 13 dB	-	-64	-58	dBc

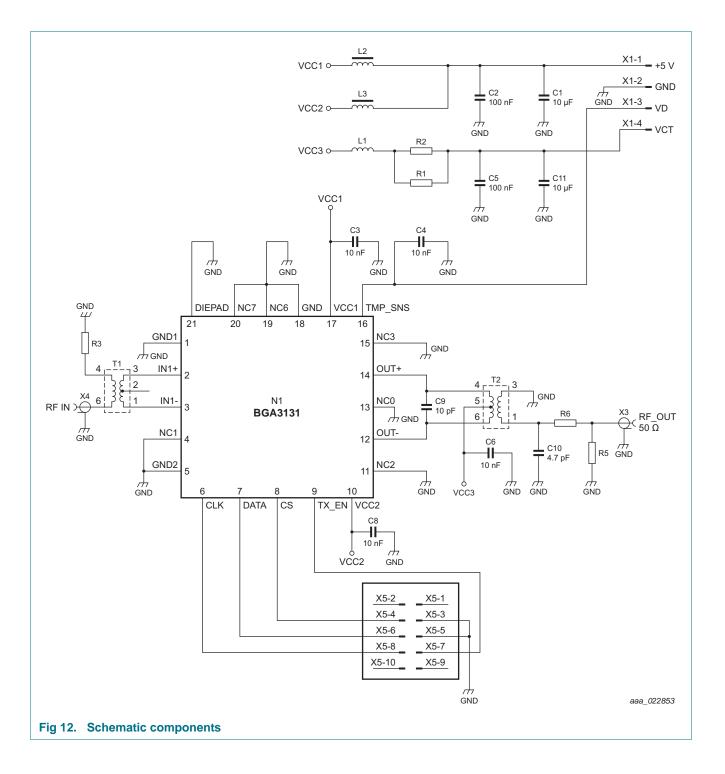
## **13. External components**

Matching the balanced output of the chip to a single-ended 75  $\Omega$  load is accomplished using a 1: 2 ratio transformer. For measurements in a 50  $\Omega$  system, R5 and R6 are added for impedance transformation from 75  $\Omega$  to 50  $\Omega$ . R5 and R6 are not required in the final application.

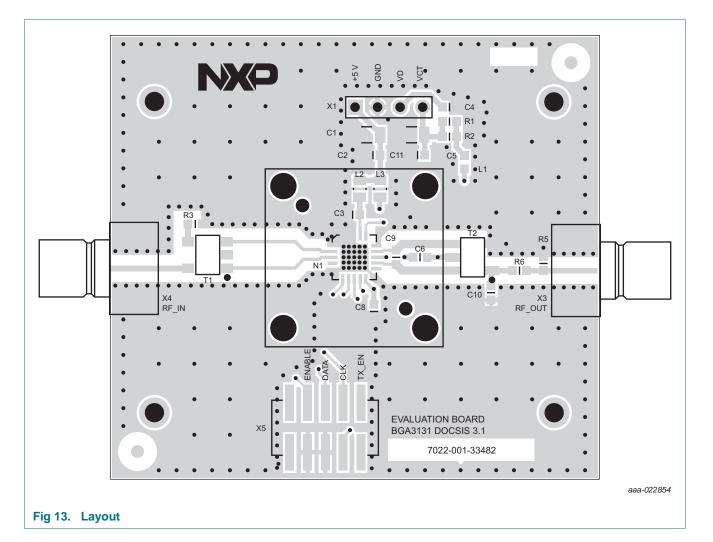
The transformer also cancels even mode distortion products and common mode signals, such as the voltage transients that occur while enabling and disabling the amplifiers.

External capacitors are needed for the functionality of the circuit, the pins are internal nodes in the output amplifier. The measured voltage on the temperature sense pin 16 at an input current of 1 mA, is related to the die temperature.

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**DOCSIS 3.1 upstream amplifier** 



#### Table 15. List of components

For application diagram, see Figure 12.

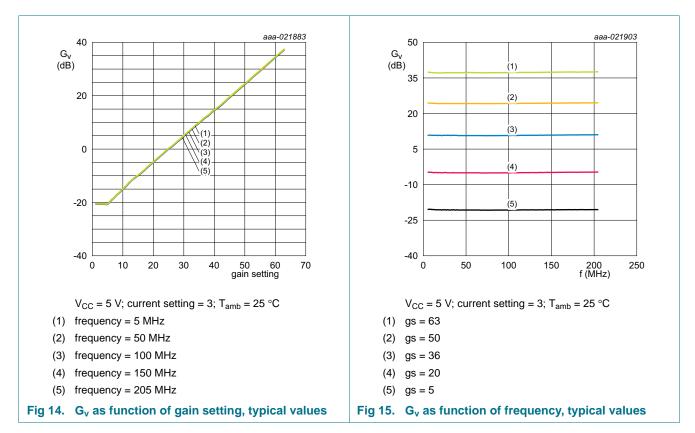
Component	Description	Value	Size	Supplier: Part No.
C1, C11	capacitor	10 μF	SMD 1206	
C2, C5	capacitor	100 nF	SMD 0603	
C3, C4, C6, C8	capacitor	10 nF	SMD 0603	
C9	capacitor	10 pF	SMD 0603	
C10	capacitor	4.7 pF	SMD 0603	
L1	place holder for optional inductor	-	-	on EVB 0 Ω mounted
L2, L3	place holder for option chokes	-	-	on EVB 0 $\Omega$ mounted
N1	amplifier	-	-	NXP: BGA3131
R1, R2	resistor	0 Ω	SMD 0603	
R3	resistor	0Ω	SMD 0603	
R5	resistor	86.6 Ω	SMD 0603	75 $\Omega$ to 50 $\Omega$ conversion for measurement purpose only
R6	resistor	43.2 Ω	SMD 0603	75 $\Omega$ to 50 $\Omega$ conversion for measurement purpose only

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# Table 15. List of components ...continued For application diagram, see Figure 12.

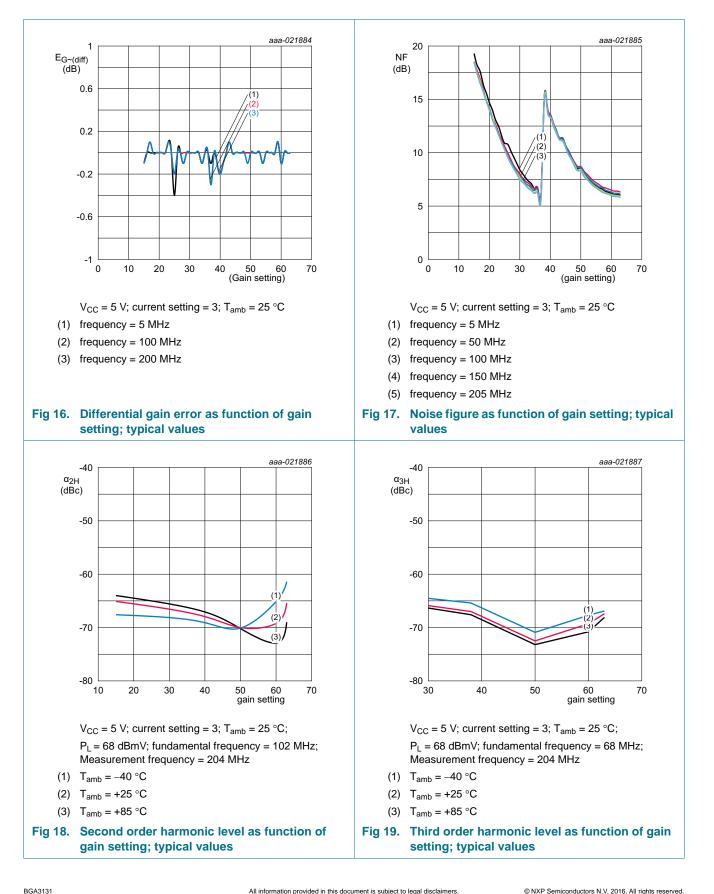
	diagram, see <u>Figure 12</u> .			
Component	Description	Value	Size	Supplier: Part No.
T1	transformer	-	-	TOKO: #617PT-1664
T2	transformer	-	-	MACOM: MABA-011056
X1	header, 4P	-	-	
X3, X4	SMA connector	-	-	
X5	header, 10P	-	-	

# 14. Application information



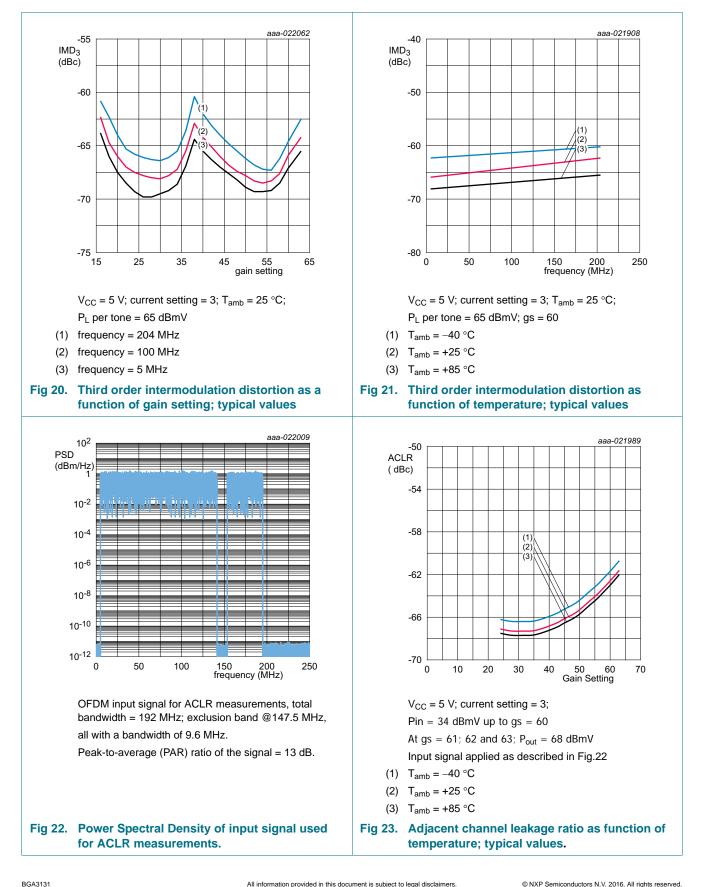
## 14.1 Graphics

### **DOCSIS 3.1 upstream amplifier**



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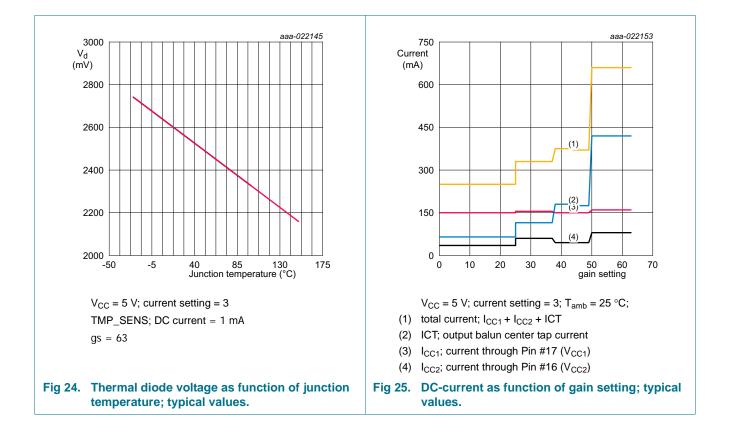


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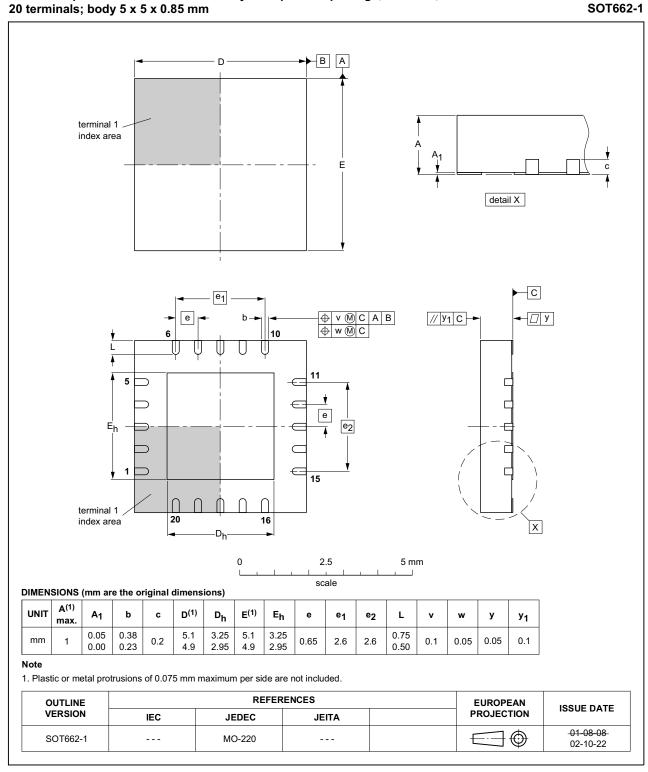
# **BGA3131**

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## 15. Package outline



#### HVQFN20: plastic thermal enhanced very thin quad flat package; no leads; 20 terminals; body 5 x 5 x 0.85 mm

Fig 26. Package outline SOT662-1 (HVQFN20)

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# **16. Handling information**

## 16.1 Moisture sensitivity

Table 16.         Moisture sensitivity level	
Test methodology	Class
JESD-22-A113	MSL 1

# **17. Abbreviations**

Table 17. Abbr	eviations
Acronym	Description
ACLR	Adjacent Channel Leakage Ratio
CATV	Community Antenna Television
CW	Continuous Wave
ESD	ElectroStatic Discharge
HVQFN	Heat sink Very thin Quad Flat pack No leads
OFDM	Orthogonal Frequency Division Multiplexing
PAPR	Peak-to-Average Power Ratio
SMA	Sub-Miniature version A
SMD	Surface-Mounted Device
ТХ	Transmission
VoIP	Voice over Internet Protocol

# **18. Revision history**

#### Table 18. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BGA3131 v.1	20160513	Product data sheet	-	-

## **19. Legal information**

## **19.1 Data sheet status**

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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